

# PXAC261002FC

## Thermally-Enhanced High Power RF LDMOS FET 100 W, 28 V, 2490 – 2690 MHz

### Description

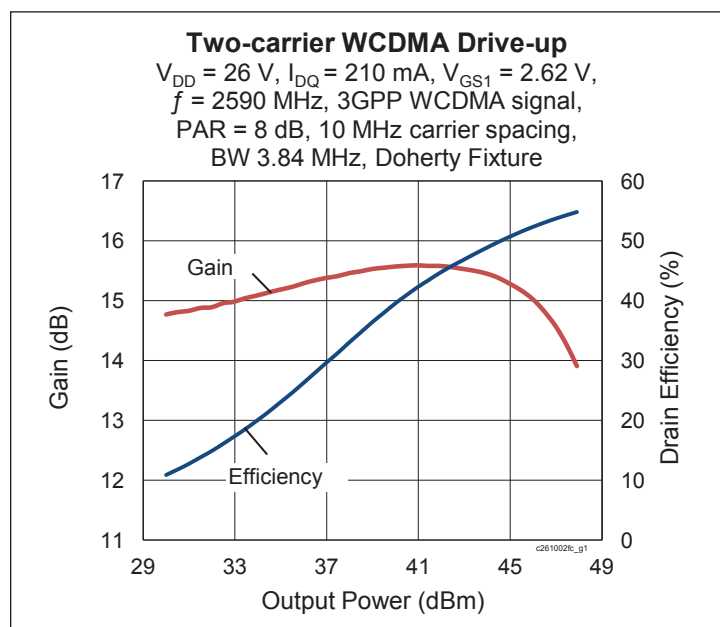
The PXAC261002FC is a 100-watt LDMOS FET with an asymmetric design intended for use in multi-standard cellular power amplifier applications in the 2496 to 2690 MHz frequency band. Features include dual-path design, high gain and a thermally-enhanced package with earless flanges. Manufactured with Wolfspeed's advanced LDMOS process, this device provides excellent thermal performance and superior reliability.



PXAC261002FC  
Package H-37248-4

### Features

- Broadband internal input and output matching
- Asymmetric design
  - Main: P1dB = 40 W Typ
  - Peak: P1dB = 70 W Typ
- Typical Pulsed CW performance, 2590 MHz, 26 V, 160  $\mu$ s, 10% duty cycle, Doherty Configuration
  - Output power at P1dB = 46.5 dBm
  - Output power at P3dB = 50.1 dBm
- Capable of handling 10:1 VSWR @28 V, 100 W (CW) output power
- Integrated ESD protection : Human Body Model, Class 1C (per JESD22-A114)
- Low thermal resistance
- Pb-free and RoHS compliant



### RF Characteristics

#### Two-carrier WCDMA Specifications (tested in Wolfspeed production Doherty test fixture)

$V_{DD} = 26$  V,  $I_{DQ} = 210$  mA,  $P_{OUT} = 18$  W avg,  $V_{GS2} = 1.4$  V,  $f_1 = 2550$  MHz,  $f_2 = 2590$  MHz, 3GPP signal, 3.84 MHz channel bandwidth, 8 dB peak/average @ 0.01% CCDF

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	$G_{ps}$	14.1	15.1	—	dB
Drain Efficiency	$\eta_D$	46	49	—	%
Intermodulation Distortion	IMD	—	-22	-21	dBc
Output PAR at 0.01% probability on CCDF (one-carrier WCDMA, 2585 MHz, 10 dB PAR)	OPAR	7.5	—	—	dB

All published data at  $T_{CASE} = 25^\circ\text{C}$  unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!

**DC Characteristics** (each side)

Characteristic	Conditions	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}$ , $I_{DS} = 10\text{ mA}$	$V_{(BR)DSS}$	65	—	—	V
Drain Leakage Current	$V_{DS} = 28\text{ V}$ , $V_{GS} = 0\text{ V}$	$I_{DSS}$	—	—	1	$\mu\text{A}$
	$V_{DS} = 63\text{ V}$ , $V_{GS} = 0\text{ V}$	$I_{DSS}$	—	—	10	$\mu\text{A}$
Gate Leakage Current	$V_{GS} = 10\text{ V}$ , $V_{DS} = 0\text{ V}$	$I_{GSS}$	—	—	1	$\mu\text{A}$
On-State Resistance	(main) $V_{GS} = 10\text{ V}$ , $V_{DS} = 0.1\text{ V}$	$R_{DS(on)}$	—	0.3	—	$\Omega$
	(peak) $V_{GS} = 10\text{ V}$ , $V_{DS} = 0.1\text{ V}$	$R_{DS(on)}$	—	0.16	—	$\Omega$
Operating Gate Voltage	(main) $V_{DS} = 26\text{ V}$ , $I_{DQ} = 210\text{ mA}$	$V_{GS}$	2.1	2.6	3.1	V
	(peak) $V_{DS} = 26\text{ V}$ , $I_{DQ} = 0\text{ mA}$	$V_{GS}$	0.9	1.4	1.9	V

**Maximum Ratings**

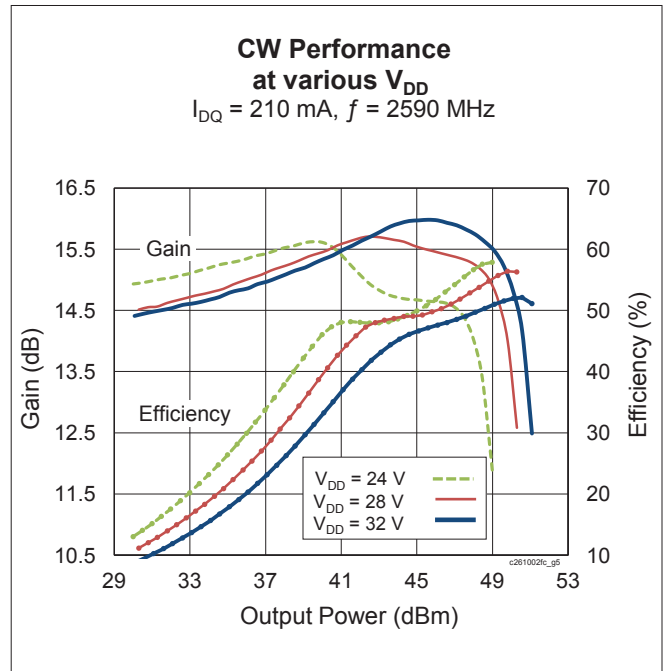
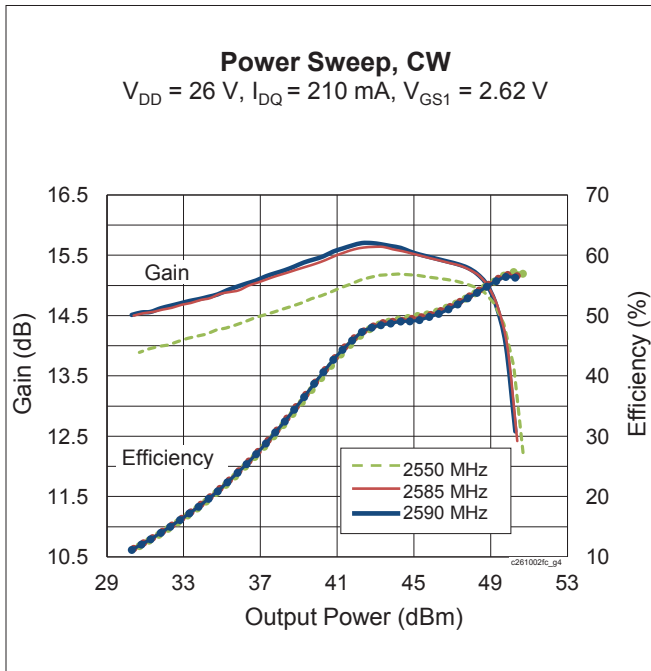
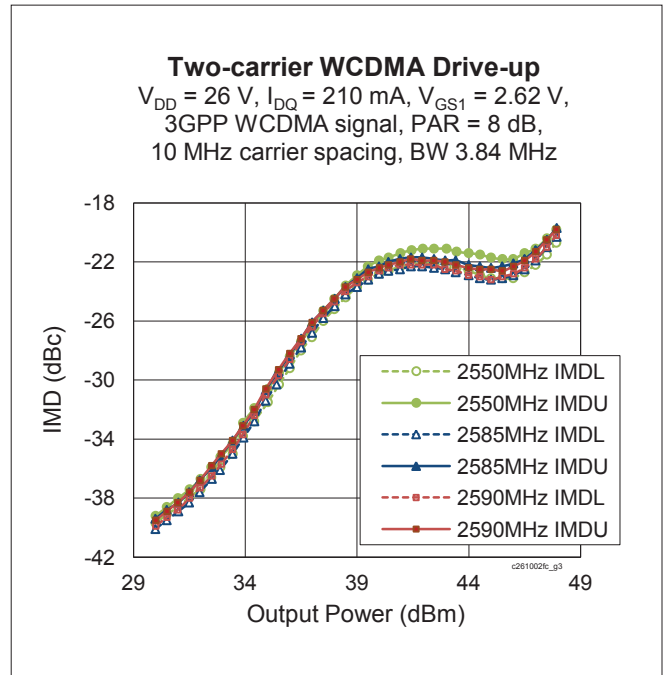
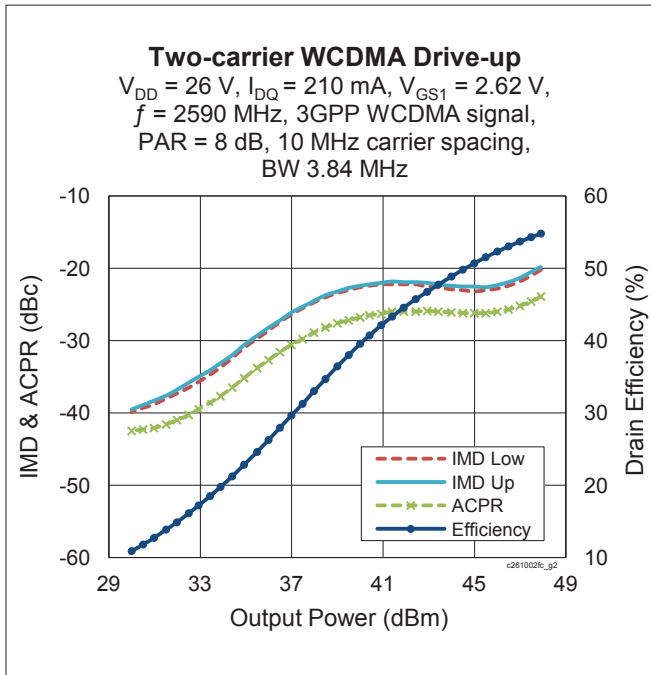
Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	65	V
Gate-Source Voltage	$V_{GS}$	-6 to +10	V
Operating Voltage	$V_{DD}$	0 to +32	V
Junction Temperature	$T_J$	225	$^{\circ}\text{C}$
Storage Temperature Range	$T_{STG}$	-65 to +150	$^{\circ}\text{C}$
Thermal Resistance (Doherty, $T_{CASE} = 70^{\circ}\text{C}$ , 100 W CW)	$R_{\theta JC}$	0.6	$^{\circ}\text{C/W}$

**Ordering Information**

Type and Version	Order Code	Package and Description	Shipping
PXAC261002FC V1 R0	PXAC261002FC-V1-R0	H-37248-4, open-cavity, push-pull, earless flange	Tape & Reel, 50 pcs
PXAC261002FC V1 R250	PXAC261002FC-V1-R250	H-37248-4, earless flange push-pull, earless flange	Tape & Reel, 250 pcs

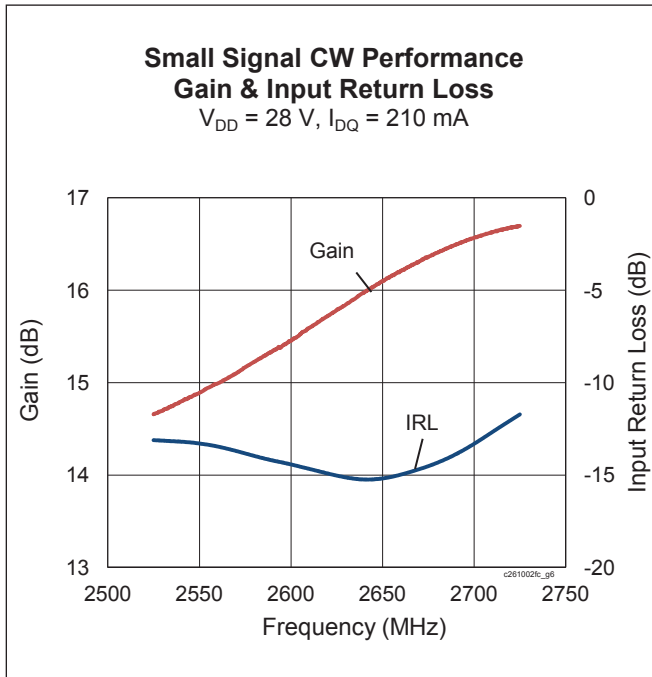


**Typical Performance** (data taken in a production Doherty test fixture)





**Typical Performance** (cont.)



**Load Pull Performance**

**Main Side Load Pull Performance** – Pulsed CW signal: 160  $\mu$ s, 10% duty cycle,  $V_{DD} = 28$  V,  $I_{DQ} = 240$  mA

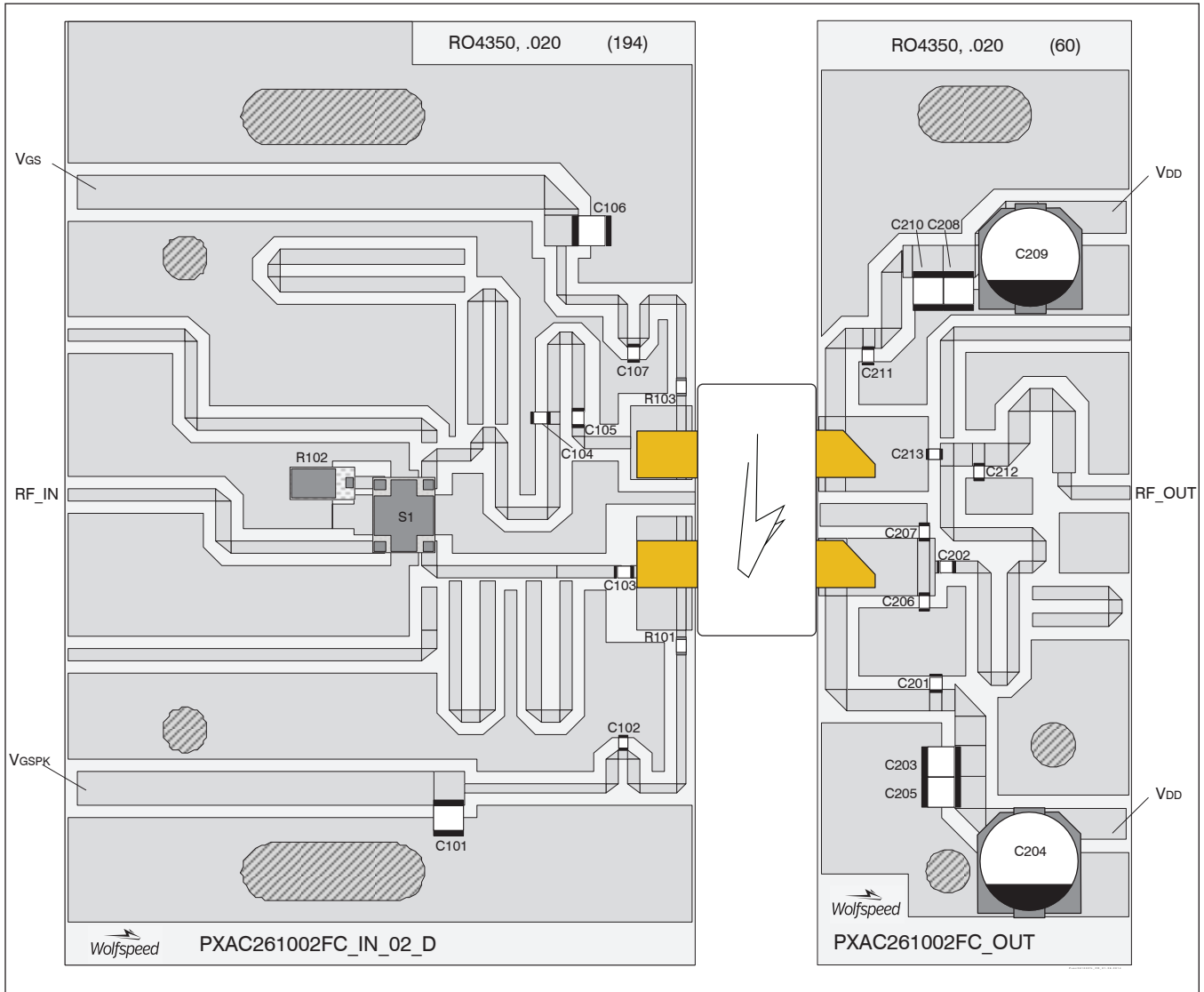
Freq [MHz]	Zs [ $\Omega$ ]	P <sub>1dB</sub>									
		Max Output Power					Max PAE				
		ZI [ $\Omega$ ]	Gain [dB]	P <sub>OUT</sub> [dBm]	P <sub>OUT</sub> [W]	PAE [%]	ZI [ $\Omega$ ]	Gain [dB]	P <sub>OUT</sub> [dBm]	P <sub>OUT</sub> [W]	PAE [%]
2540	13.3 - j23.8	5.7 - j10.9	16.8	46.58	45	50.3	10.9 - j7.1	19.1	45.1	32	59.5
2590	16.5 - j22.0	5.9 - j11.5	16.7	46.44	44	50.3	9.7 - j7.6	18.7	45.3	34	58.5
2640	21 - j24.7	6.4 - j11.5	16.8	46.35	43	50.0	10 - j6.2	19.1	44.9	31	58.0

**Peak Side Load Pull Performance** – Pulsed CW signal: 160  $\mu$ s, 10% duty cycle, 28 V,  $V_{GS1} = 1.4$  V

Freq [MHz]	Zs [ $\Omega$ ]	P <sub>1dB</sub>									
		Max Output Power					Max PAE				
		ZI [ $\Omega$ ]	Gain [dB]	P <sub>OUT</sub> [dBm]	P <sub>OUT</sub> [W]	PAE [%]	ZI [ $\Omega$ ]	Gain [dB]	P <sub>OUT</sub> [dBm]	P <sub>OUT</sub> [W]	PAE [%]
2540	3.8-j12.1	11.8-j7.3	13.0	50	100	53.5	5.2-j5.3	14.4	48.4	69	63.4
2590	5.2-j12.8	13-j5.4	12.8	50	100	53.4	5.7-j5.6	14.2	48.5	71	62.2
2640	5.8-j13.3	14-j3.9	12.8	49.9	98	52.9	6.6-j6	14.2	48.4	69	61.0



Reference Circuit, 2545 – 2595 MHz



Reference circuit assembly diagram (not to scale)



**Reference Circuit** (cont.)

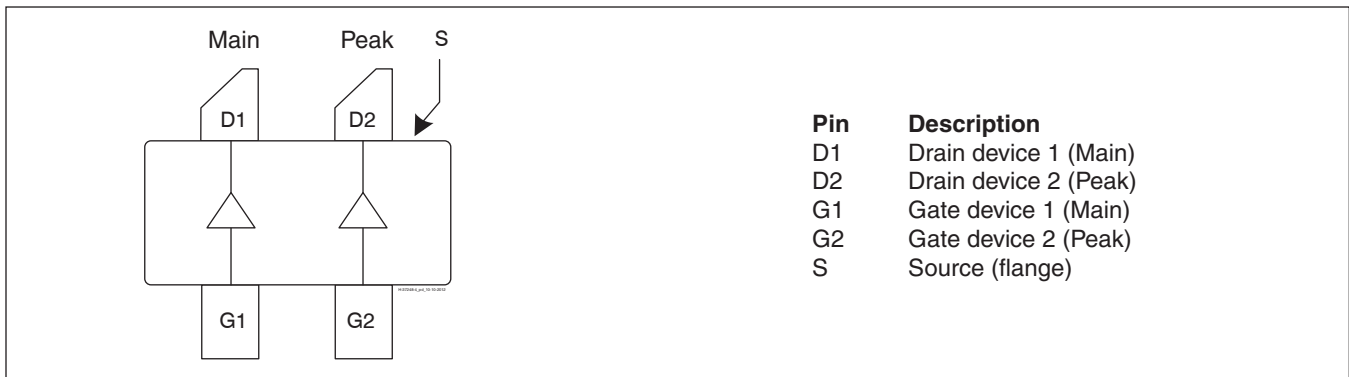
**Reference Circuit Assembly**

DUT	PXAC261002FC V1
Test Fixture Part No.	LTA/PXAC261002FC V1
PCB	Rogers 4350, 0.508 mm [0.020"] thick, 2 oz. copper, $\epsilon_r = 3.66$ , $f = 2545 - 2595$ MHz
Find Gerber files for this test fixture on the Wolfspeed Web site at <a href="http://www.wolfspeed.com/RF">http://www.wolfspeed.com/RF</a>	

**Components Information**

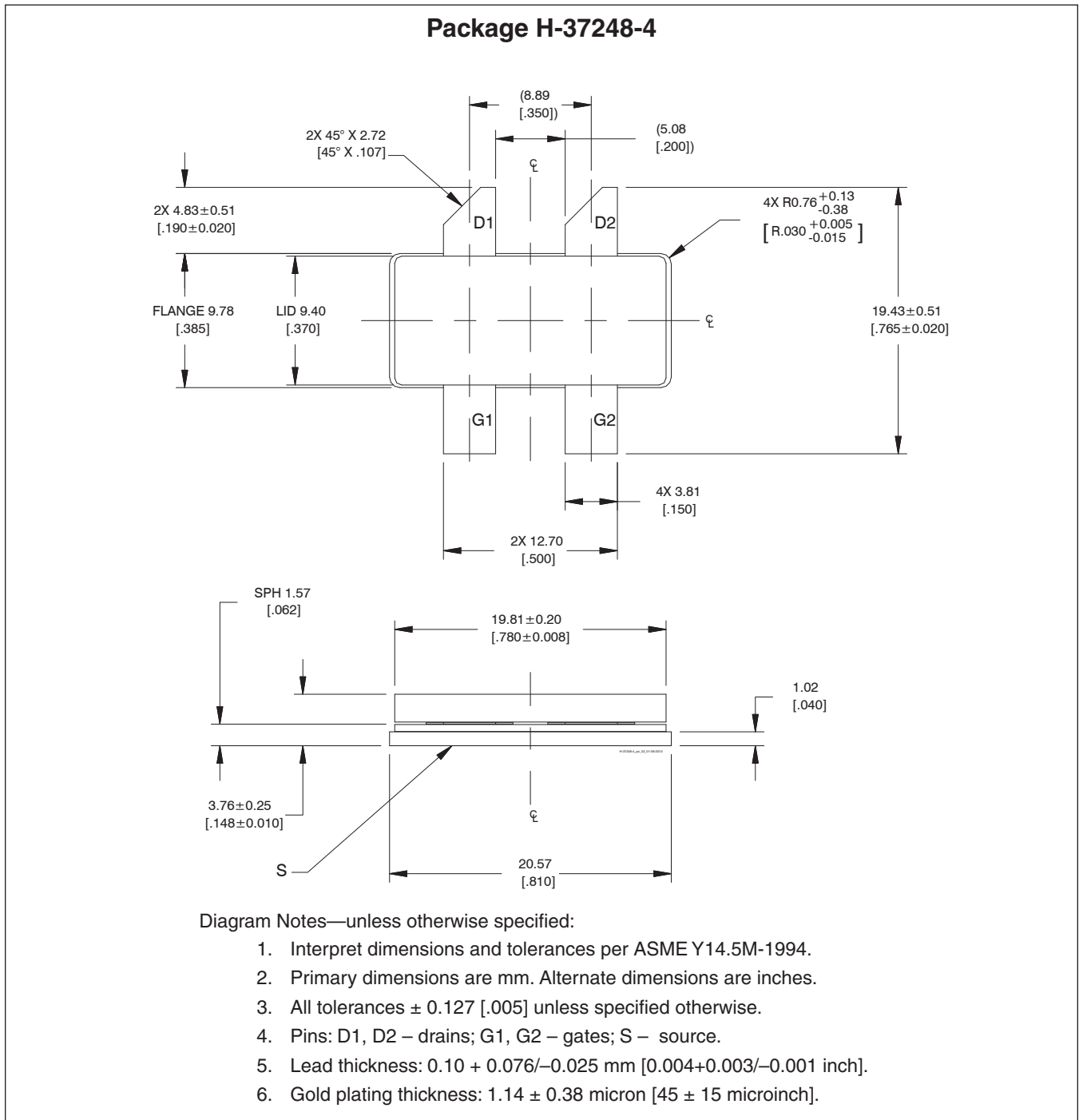
Component	Description	Suggested Manufacturer	P/N
<b>Input</b>			
C101, C106	Capacitor, 10 $\mu$ F	Taiyo Yuden	UMK325C7106MM-T
C102	Capacitor, 18 pF	ATC	ATC800A180JT250T
C103	Capacitor, 1.6 pF	ATC	ATC800A1R6CT250T
C104	Capacitor, 0.6 pF	ATC	ATC800A0R6CT250T
C105, C107	Capacitor, 12 pF	ATC	ATC800A120JT250T
R101, R103	Resistor, 10 ohm	Panasonic Electronic Components	ERJ-3GEYJ100V
R102	Resistor, 50 ohm	Anaren	C16A50Z4
S1	Hybrid coupler	Anaren	X3C26P1-03S
<b>Output</b>			
C201, C202	Capacitor, 12 pF	ATC	ATC800A120KT250T
C203, C205, C208, C210	Capacitor, 10 $\mu$ F	Taiyo Yuden	UMK325C7106MM-T
C204, C209	Capacitor, 220 $\mu$ F	Panasonic Electronic Components	EEE-FP1V221A
C206	Capacitor, 0.5 pF	ATC	ATC800A0R5CT250T
C207	Capacitor, 0.6 pF	ATC	ATC800A0R6CT250T
C211	Capacitor, 12 pF	ATC	ATC800A120JT250T
C212	Capacitor, 0.4 pF	ATC	ATC800A0R4CT250T
C213	Capacitor, 3.9 pF	ATC	ATC800A3R9CT250T

**Pinout Diagram** (top view)



Lead connections for PXAC261002FC

Package Outline Specifications



## Revision History

Revision	Date	Data Sheet Type	Page	Subjects (major changes since last revision)
01	2013-11-01	Advance	All	Data Sheet reflects advance specification for product development
02	2014-01-28	Production	All All	Data Sheet reflects released product specification Revised all data and includes final specs, typical performance graphs, loadpull, reference circuit
03	2014-03-26	Production	1	Corrected frequency range. Removed "doherty" from second feature. Updated feature 2.
03.1	2014-04-04	Production	1	Removed bullet point 4 (extra lines) from Features section.
03.2	2016-06-07	Production	1	Added OPAR to RF table.
03.3	2016-06-15	Production	1	Adjust OPAR information.
04	2018-07-03	Production	All	Converted to Wolfsped Data Sheet.

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## Notes

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